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Vishay General Semiconductor

# High Voltage Trench MOS Barrier Schottky Rectifier



| PRIMARY CHARACTERISTICS |                  |  |  |
|-------------------------|------------------|--|--|
| I <sub>F(AV)</sub>      | 2.0 A            |  |  |
| V <sub>RRM</sub>        | 200 V            |  |  |
| I <sub>FSM</sub>        | 40 A             |  |  |
| $V_F$ at $I_F$ = 2.0 A  | 0.65 V           |  |  |
| T <sub>J</sub> max.     | 150 °C           |  |  |
| Package                 | DO-204AL (DO-41) |  |  |
| Diode variations        | Single           |  |  |

# FEATURES

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- High efficiency operation
- Solder dip 275 °C max. 10 s, per JESD 22-B106
   FREE
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

# **TYPICAL APPLICATIONS**

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters or polarity protection application.

### **MECHANICAL DATA**

Case: DO-204AL (DO-41)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: Color band denotes the cathode end

| <b>MAXIMUM RATINGS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)                |                                   |               |      |  |
|---|-----------------------------------|---------------|------|--|
| PARAMETER   | SYMBOL                            | VSB2200S      | UNIT |  |
| Max. repetitive peak reverse voltage  | V <sub>RRM</sub>                  | 200           | V    |  |
| Max. average forward rectified current (fig. 1) (1)                                   | I <sub>F(AV)</sub>                | 2.0           | A    |  |
| Peak forward surge current 8.3 ms single half<br>sine-wave superimposed on rated load | I <sub>FSM</sub>                  | 40            | А    |  |
| Voltage rate of change (rated V <sub>R</sub> )  | dV/dt                             | 10 000        | V/µs |  |
| Operating junction and storage temperature range                                      | T <sub>J</sub> , T <sub>STG</sub> | - 40 to + 150 | °C   |  |

#### Note

<sup>(1)</sup> Units mounted on PCB with 2 mm x 2 mm copper pad areas 0.375" (9.5 mm) lead length, free air

| <b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted) |                          |                         |                 |            |      |      |
|---|--------------------------|-------------------------|-----------------|------------|------|------|
| PARAMETER   | TEST CO                  | TEST CONDITIONS         |                 | TYP.       | MAX. | UNIT |
| Breakdown voltage   | I <sub>R</sub> = 1.0 mA  | T <sub>A</sub> = 25 °C  | V <sub>BR</sub> | 200 (min.) | -    |      |
| Instantaneous forward voltage <sup>(1)</sup>                                      | I <sub>F</sub> = 2.0 A   | T <sub>A</sub> = 25 °C  | V <sub>F</sub>  | 0.97       | 1.23 | V    |
|   | $I_{\rm F} = 2.0 \rm{A}$ | T <sub>A</sub> = 125 °C |                 | 0.65       | 0.73 |      |
| Reverse current per diode <sup>(2)</sup>  | V 200 V                  | T <sub>A</sub> = 25 °C  | I <sub>R</sub>  | 0.8        | 40   | μA   |
|   | V <sub>R</sub> = 200 V   | T <sub>A</sub> = 125 °C |                 | 0.6        | 4    | mA   |
| Typical juntion capacitance   | 4.0 V, 1 MHz             |                         | CJ              | 110        | -    | pF   |

### Notes

<sup>(1)</sup> Pulse test: 300 µs pulse width, 1 % duty cycle

<sup>(2)</sup> Pulse test: Pulse width  $\leq$  40 ms

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| <b>THERMAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted) |                     |          |      |  |
|--|---------------------|----------|------|--|
| PARAMETER  | SYMBOL              | VSB2200S | UNIT |  |
| Typical thermal resistance <sup>(1)</sup>                                      | R <sub>0JA</sub>    | 88       | °C/W |  |
| Typical mermanesistance **   | $R_{	ext{	heta}JL}$ | 20       | 0/10 |  |

Note

<sup>(1)</sup> Units mounted on PCB with 2 mm x 2 mm copper pad areas 0.375" (9.5 mm) lead length, free air

| ORDERING INFORMATION (Example) |                 |                        |               |                                  |  |  |
|--------------------------------|-----------------|------------------------|---------------|----------------------------------|--|--|
| PREFERRED P/N                  | UNIT WEIGHT (g) | PREFERRED PACKAGE CODE | BASE QUANTITY | DELIVERY MODE                    |  |  |
| VSB2200S-M3/54                 | 0.34            | 54                     | 5500          | 13" diameter paper tape and reel |  |  |
| VSB2200S-M3/73                 | 0.34            | 73                     | 3000          | Ammo pack packaging              |  |  |

## **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

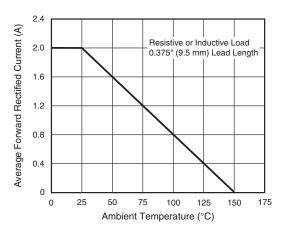


Fig. 1 - Maximum Forward Current Derating Curve

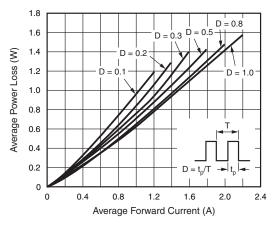


Fig. 2 - Forward Power Loss Characteristics

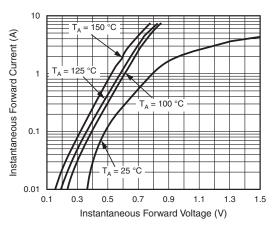


Fig. 3 - Typical Instantaneous Forward Characteristics

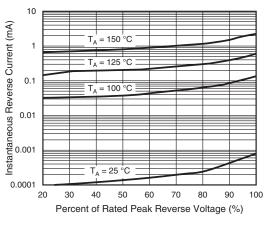


Fig. 4 - Typical Reverse Characteristics

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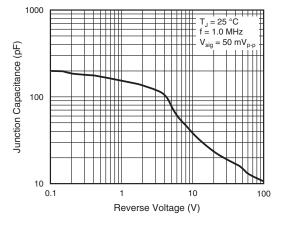


Fig. 5 - Typical Junction Capacitance

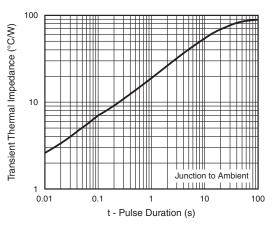
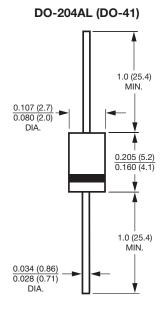


Fig. 6 - Typical Transient Thermal Impedance

## **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)



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